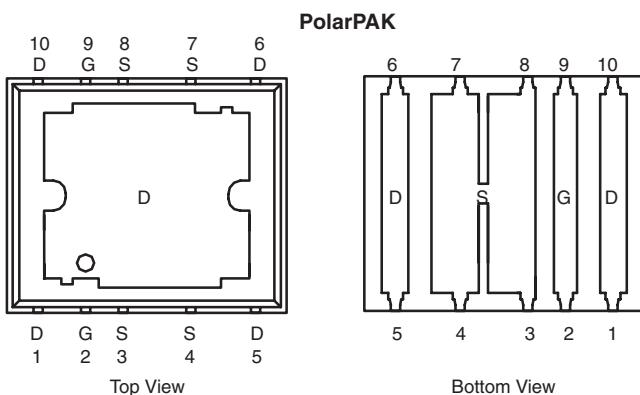


## N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY				
$V_{DS}$ (V)	$R_{DS(on)}$ ( $\Omega$ )	$I_D$ (A) <sup>a</sup>		$Q_g$ (Typ.)
		Silicon Limit	Package Limit	
30	0.0042 at $V_{GS} = 10$ V	120	50	33 nC
	0.0048 at $V_{GS} = 4.5$ V	112	50	

Package Drawing

[www.vishay.com/doc?73398](http://www.vishay.com/doc?73398)



Top surface is connected to pins 1, 5, 6, and 10

Ordering Information: SiE830DF-T1-E3 (Lead (Pb)-free)

SiE830DF-T1-GE3 (Lead (Pb)-free and Halogen-free)

### FEATURES

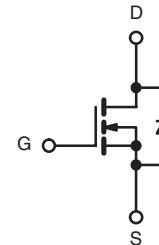
- Halogen-free According to IEC 61249-2-21 Definition
- Extremely Low  $Q_{gd}$  WFET® Technology for Low Switching Losses
- Ultra Low Thermal Resistance Using Top-Exposed PolarPAK® Package for Double-Sided Cooling
- Leadframe-Based New Encapsulated Package
  - Die Not Exposed
  - Same Layout Regardless of Die Size
- Low  $Q_{gd}/Q_{gs}$  Ratio Helps Prevent Shoot-Through
- 100 %  $R_g$  and UIS Tested
- Compliant to RoHS directive 2002/95/EC



RoHS  
COMPLIANT  
HALOGEN  
**FREE**  
Available

### APPLICATIONS

- VRM
- Point-of-Load
- Synchronous Rectification



N-Channel MOSFET

For Related Documents

[www.vishay.com/ppg?74422](http://www.vishay.com/ppg?74422)

ABSOLUTE MAXIMUM RATINGS $T_A = 25$ °C, unless otherwise noted			
Parameter	Symbol	Limit	Unit
Drain-Source Voltage	$V_{DS}$	30	V
Gate-Source Voltage	$V_{GS}$	$\pm 12$	
Continuous Drain Current ( $T_J = 150$ °C)	$I_D$	120 (Silicon Limit)	A
		50 <sup>a</sup> (Package Limit)	
		50 <sup>a</sup>	
		27 <sup>b, c</sup>	
		21.6 <sup>b, c</sup>	
Pulsed Drain Current	$I_{DM}$	80	
Continuous Source-Drain Diode Current	$I_S$	50 <sup>a</sup>	
		4.3 <sup>b, c</sup>	
Single Pulse Avalanche Current	$I_{AS}$	30	A
Avalanche Energy	$E_{AS}$	45	mJ
Maximum Power Dissipation	$P_D$	104	W
		66	
		5.2 <sup>b, c</sup>	
		3.3 <sup>b, c</sup>	
Operating Junction and Storage Temperature Range	$T_J, T_{stg}$	- 55 to 150	
Soldering Recommendations (Peak Temperature) <sup>d, e</sup>		260	°C

Notes:

- a. Package limited is 50 A.
- b. Surface Mounted on 1" x 1" FR4 board.
- c. t = 10 s.
- d. See Solder Profile ([www.vishay.com/doc?73257](http://www.vishay.com/doc?73257)). The PolarPAK is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- e. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

**THERMAL RESISTANCE RATINGS**

Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient <sup>a, b</sup>	Steady State	$R_{thJA}$	20	24	°C/W
Maximum Junction-to-Case (Drain Top) <sup>a</sup>		$R_{thJC}$ (Drain)	1	1.2	
Maximum Junction-to-Case (Source) <sup>a, c</sup>		$R_{thJC}$ (Source)	2.8	3.4	

Notes:

- a. Surface Mounted on 1" x 1" FR4 board.
- b. Maximum under Steady State conditions is 68 °C/W.
- c. Measured at source pin (on the side of the package).

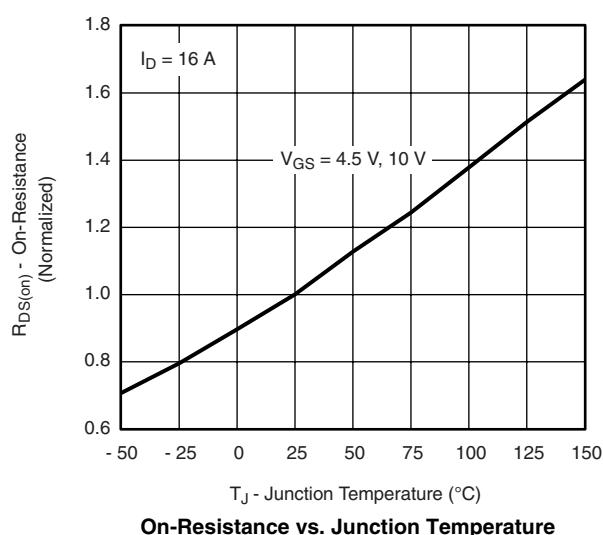
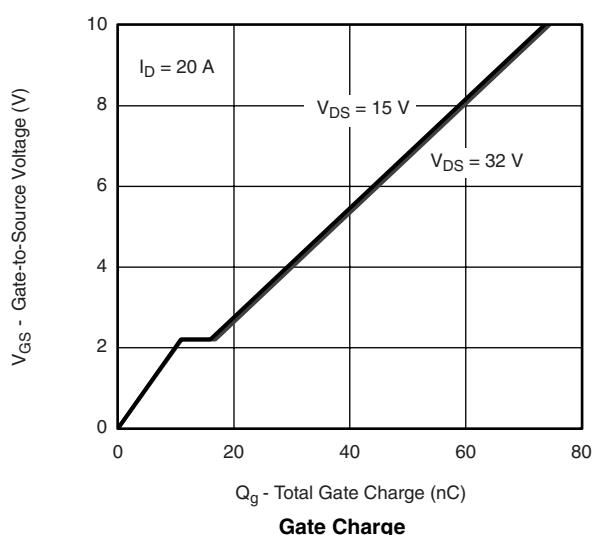
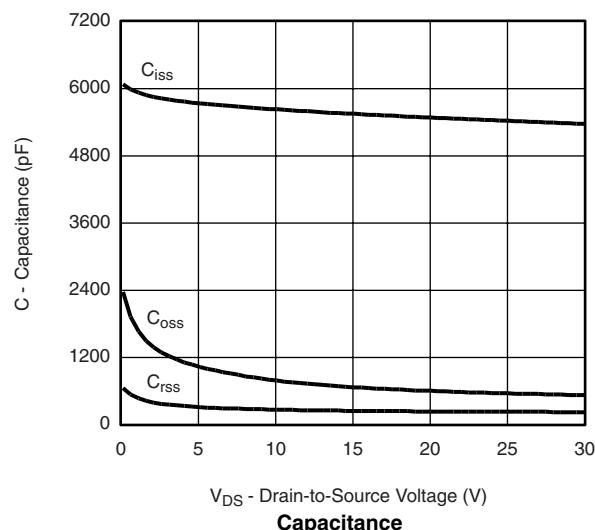
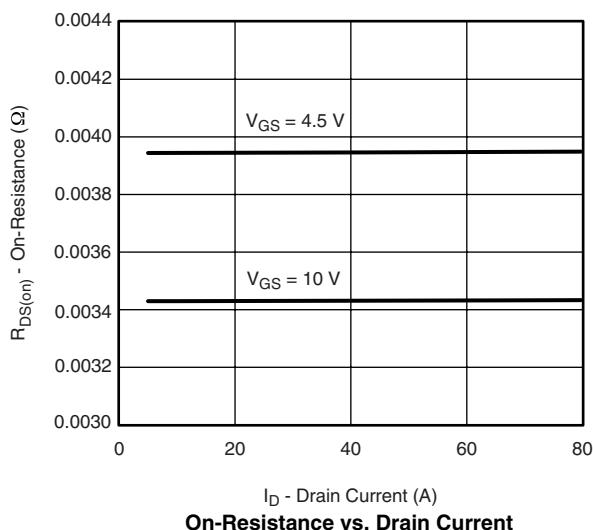
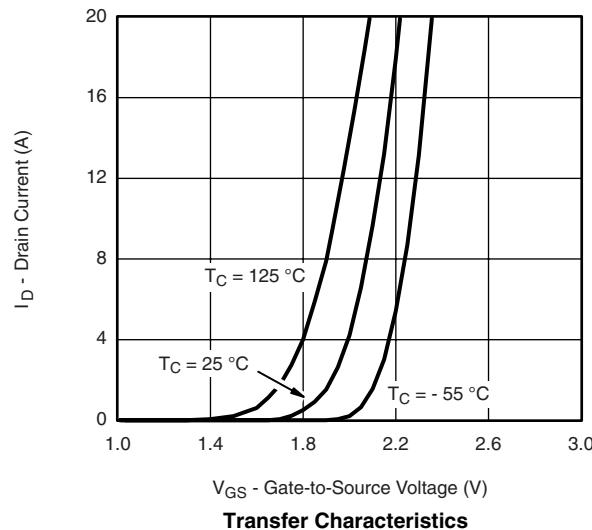
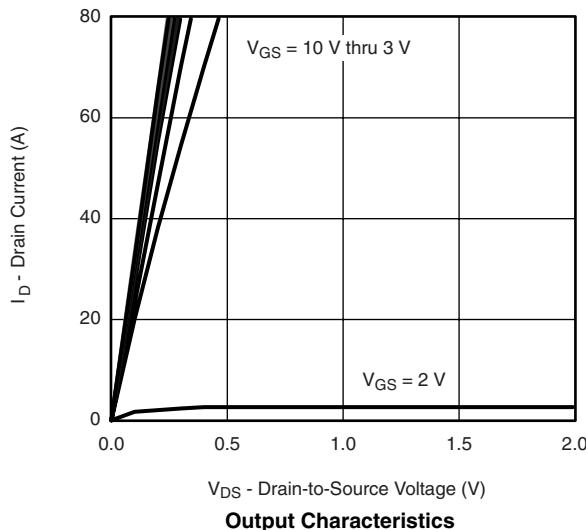
**SPECIFICATIONS**  $T_J = 25$  °C, unless otherwise noted

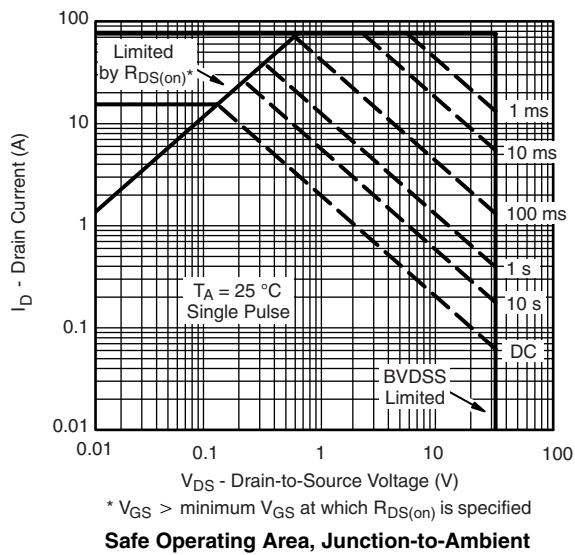
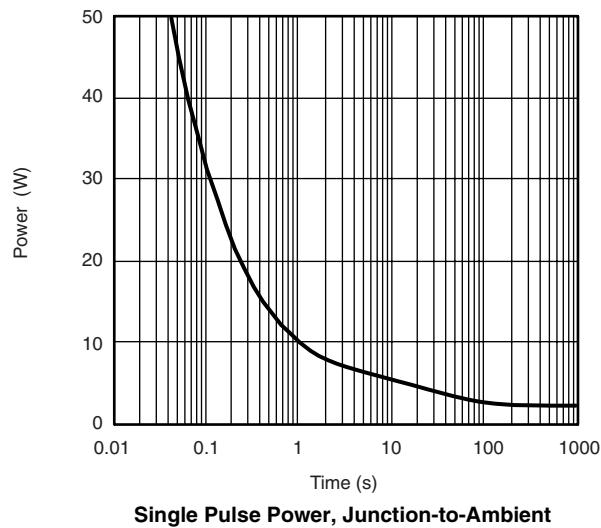
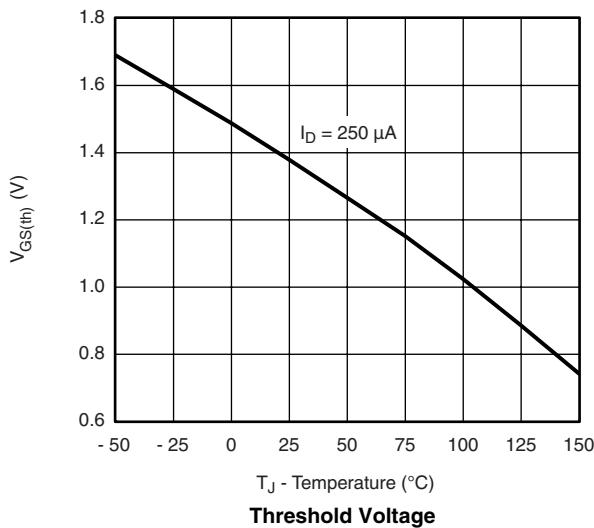
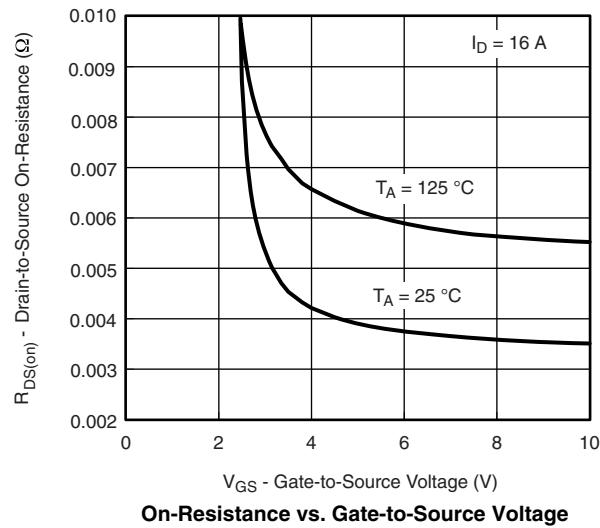
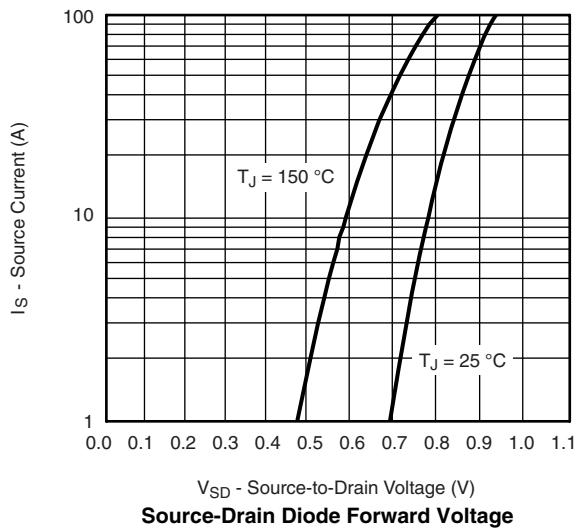
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
<b>Static</b>						
Drain-Source Breakdown Voltage	$V_{DS}$	$V_{GS} = 0$ V, $I_D = 250$ μA	30			V
$V_{DS}$ Temperature Coefficient	$\Delta V_{DS}/T_J$	$I_D = 250$ μA		30		mV/°C
$V_{GS(th)}$ Temperature Coefficient	$\Delta V_{GS(th)}/T_J$			- 4.8		
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 250$ μA	0.6	1.4	2	V
Gate-Source Leakage	$I_{GSS}$	$V_{DS} = 0$ V, $V_{GS} = \pm 12$ V			± 100	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 30$ V, $V_{GS} = 0$ V			1	μA
		$V_{DS} = 30$ V, $V_{GS} = 0$ V, $T_J = 55$ °C			10	
On-State Drain Current <sup>a</sup>	$I_{D(on)}$	$V_{DS} \geq 5$ V, $V_{GS} = 10$ V	25			A
Drain-Source On-State Resistance <sup>a</sup>	$R_{DS(on)}$	$V_{GS} = 10$ V, $I_D = 16$ A		0.0035	0.0042	Ω
		$V_{GS} = 4.5$ V, $I_D = 15$ A		0.0039	0.0048	
Forward Transconductance <sup>a</sup>	$g_{fs}$	$V_{DS} = 15$ V, $I_D = 16$ A		95		S
<b>Dynamic<sup>b</sup></b>						
Input Capacitance	$C_{iss}$	$V_{DS} = 15$ V, $V_{GS} = 0$ V, $f = 1$ MHz		5500		pF
Output Capacitance	$C_{oss}$			650		
Reverse Transfer Capacitance	$C_{rss}$			220		
Total Gate Charge	$Q_g$	$V_{DS} = 15$ V, $V_{GS} = 10$ V, $I_D = 20$ A		75	115	nC
Gate-Source Charge	$Q_{gs}$	$V_{DS} = 15$ V, $V_{GS} = 4.5$ V, $I_D = 20$ A		33	50	
Gate-Drain Charge	$Q_{gd}$			11		
Gate Resistance	$R_g$			5.1		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 15$ V, $R_L = 1.5$ Ω $I_D \cong 10$ A, $V_{GEN} = 4.5$ V, $R_g = 1$ Ω		1.0	1.5	Ω
Rise Time	$t_r$			35	55	ns
Turn-Off Delay Time	$t_{d(off)}$			105	160	
Fall Time	$t_f$			70	105	
Turn-On Delay Time	$t_{d(on)}$			95	145	
Rise Time	$t_r$			15	25	
Turn-Off Delay Time	$t_{d(off)}$			40	60	
Fall Time	$t_f$			45	70	
<b>Drain-Source Body Diode Characteristics</b>						
Continuous Source-Drain Diode Current	$I_S$	$T_C = 25$ °C			50	A
Pulse Diode Forward Current <sup>a</sup>	$I_{SM}$				80	
Body Diode Voltage	$V_{SD}$	$I_S = 10$ A		0.8	1.2	V
Body Diode Reverse Recovery Time	$t_{rr}$	$I_F = 10$ A, $dl/dt = 100$ A/μs, $T_J = 25$ °C		40	60	ns
Body Diode Reverse Recovery Charge	$Q_{rr}$			40	60	
Reverse Recovery Fall Time	$t_a$			22		ns
Reverse Recovery Rise Time	$t_b$			18		

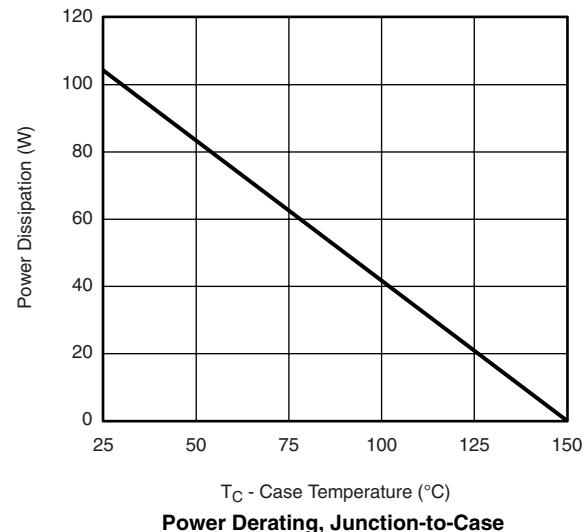
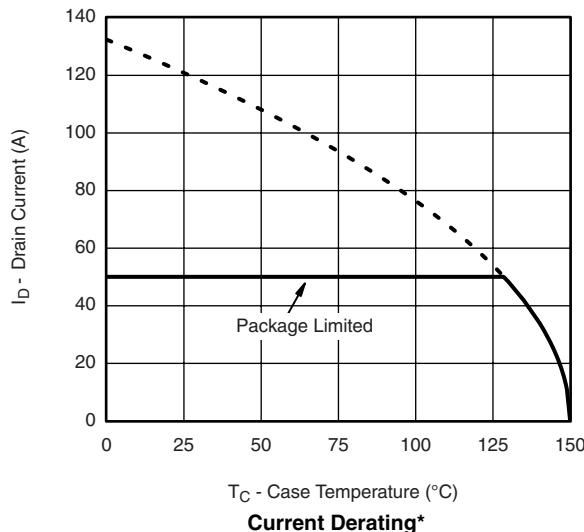
Notes:

- a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2 %
- b. Guaranteed by design, not subject to production testing.

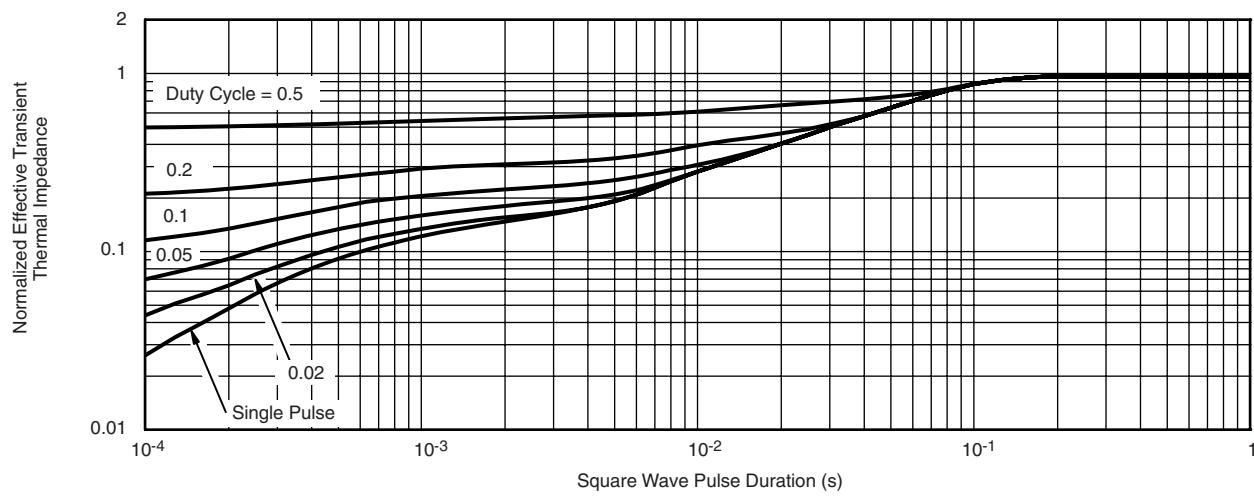
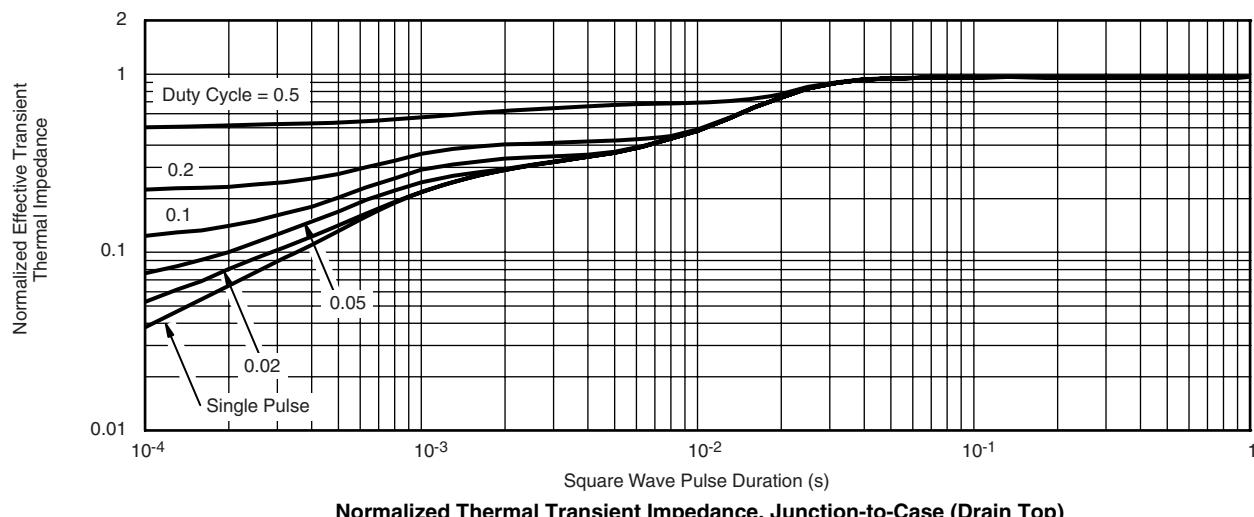
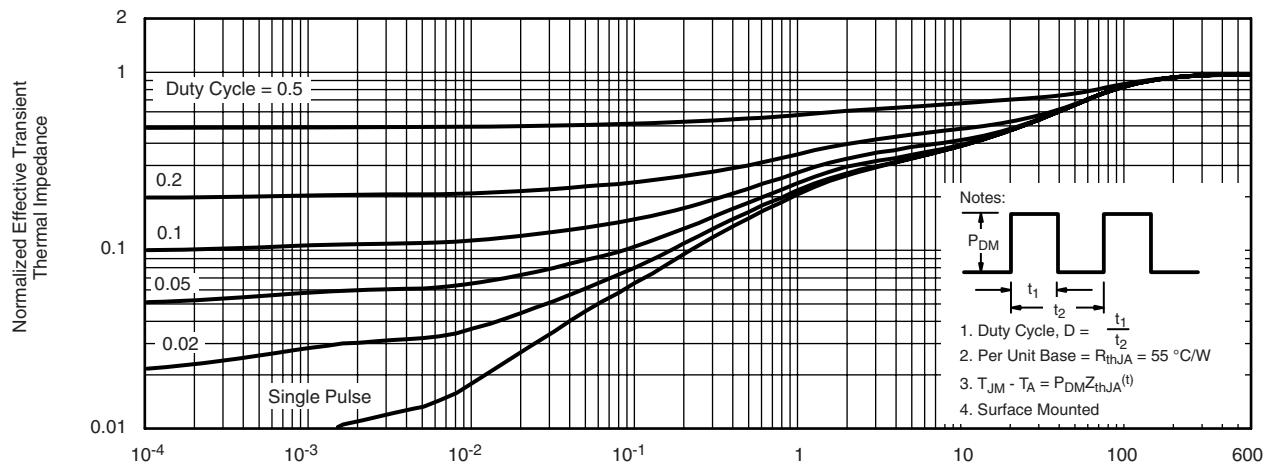
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted


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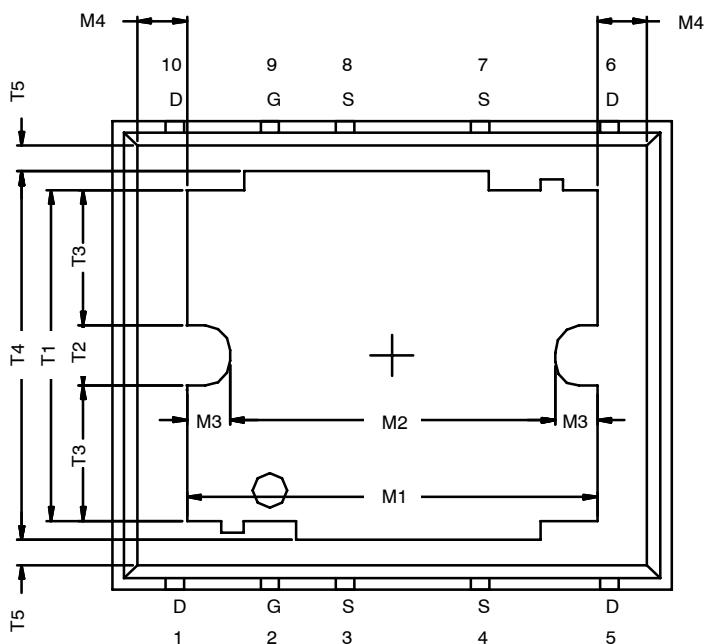
**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted


\* The power dissipation  $P_D$  is based on  $T_{J(\max)} = 150$  °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted

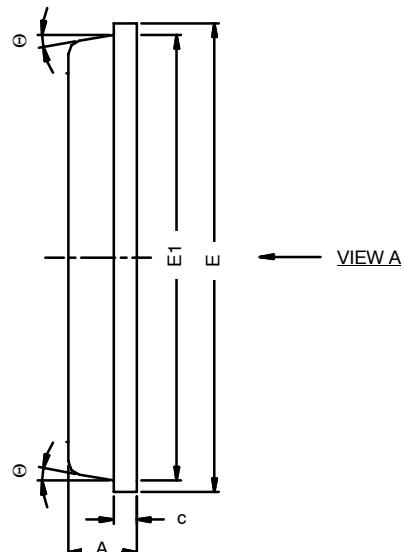
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see [www.vishay.com/ppg?74422](http://www.vishay.com/ppg?74422).

### PolarPAK™ (Option S)

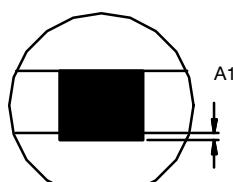
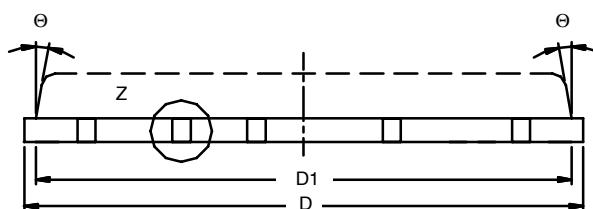


(Top View)

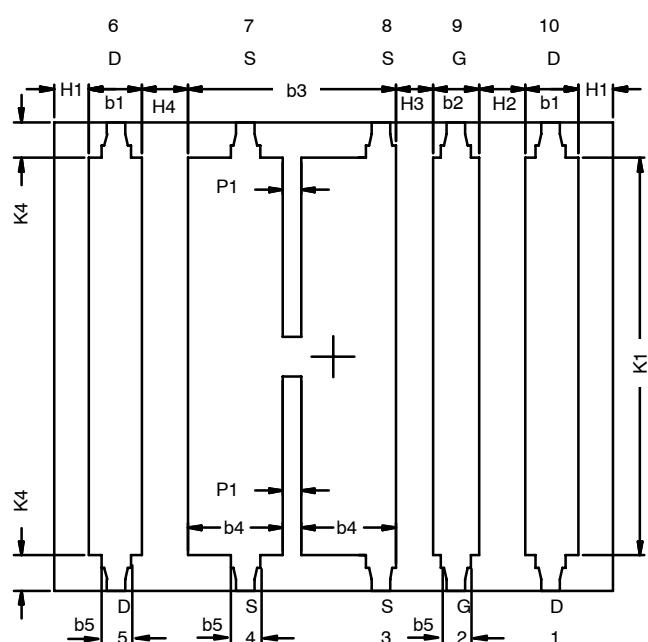
Product datasheet/information page contain links to applicable package drawing.



VIEW A



DETAIL Z



VIEW A

(Bottom View)

# Package Information

Vishay Siliconix

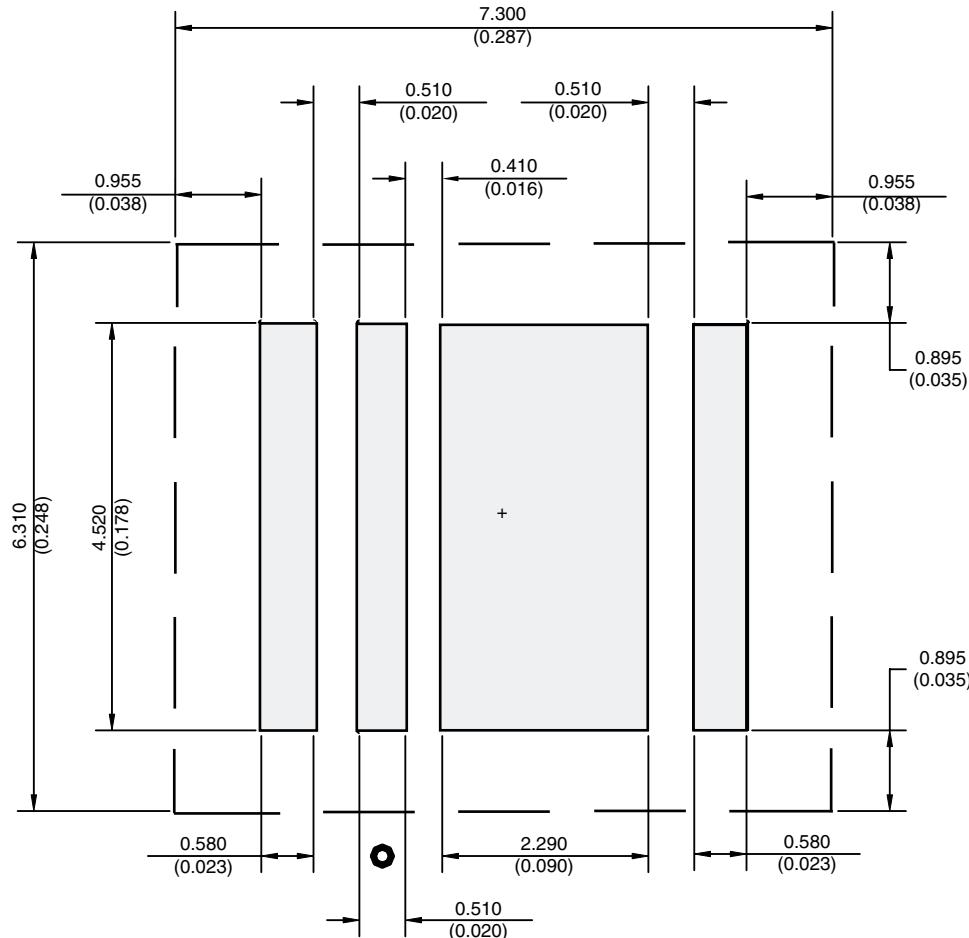


Dim	MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max
<b>A</b>	0.75	0.80	0.85	0.030	0.031	0.033
<b>A1</b>	0.00	—	0.05	0.000	—	0.002
<b>b1</b>	0.48	0.58	0.68	0.019	0.023	0.027
<b>b2</b>	0.41	0.51	0.61	0.016	0.020	0.024
<b>b3</b>	2.19	2.29	2.39	0.086	0.090	0.094
<b>b4</b>	0.89	1.04	1.19	0.035	0.041	0.047
<b>b5</b>	0.23	0.33	0.43	0.009	0.013	0.017
<b>c</b>	0.20	0.25	0.30	0.008	0.010	0.012
<b>D</b>	6.00	6.15	6.30	0.236	0.242	0.248
<b>D1</b>	5.74	5.89	6.04	0.226	0.232	0.238
<b>E</b>	5.01	5.16	5.31	0.197	0.203	0.209
<b>E1</b>	4.75	4.90	5.05	0.187	0.193	0.199
<b>H1</b>	0.23	—	—	0.009	—	—
<b>H2</b>	0.45	—	0.56	0.020	—	0.022
<b>H3</b>	0.31	0.41	0.51	0.012	0.016	0.020
<b>H4</b>	0.45	—	0.56	0.020	—	0.022
<b>K1</b>	4.22	4.37	4.52	0.166	0.172	0.178
<b>K4</b>	0.24	—	—	0.009	—	—
<b>M1</b>	4.30	4.50	4.70	0.169	0.177	0.185
<b>M2</b>	3.43	3.58	3.73	0.135	0.141	0.147
<b>M3</b>	0.22	—	—	0.009	—	—
<b>M4</b>	0.05	—	—	0.002	—	—
<b>P1</b>	0.15	0.20	0.25	0.006	0.008	0.010
<b>T1</b>	3.48	3.64	4.10	0.137	0.143	0.150
<b>T2</b>	0.56	0.76	0.95	0.022	0.030	0.037
<b>T3</b>	1.20	—	—	0.051	—	—
<b>T4</b>	3.90	—	—	0.154	—	—
<b>T5</b>	0	0.18	0.36	0.000	0.007	0.014
<b>Θ</b>	0°	10°	12°	0°	10°	12°

ECN: S-51049 Rev. B, 13-Jun-05  
DWG: 5947

Note: Millimeters govern over inches

## RECOMMENDED MINIMUM PADS FOR PolarPAK® Option L and S



Recommended Minimum for PolarPAK Option L and S

Dimensions in mm/(Inches)

No External Traces within Broken Lines

Dot indicates Gate Pin (Part Marking)



### Disclaimer

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### Material Category Policy

**Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.**

**Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.**

**Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.**